
2SJ317

Silicon P-Channel MOS FET

HITACHI

Application

High speed power switching

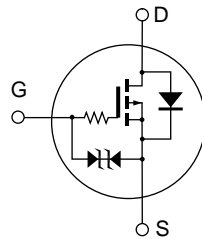
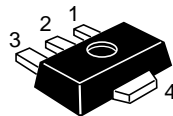
Low voltage operation

Features

- Very low on-resistance
- High speed switching
- Suitable for camera or VTR motor drive circuit, power switch, solenoid drive and etc.

Outline

UPAK



1. Gate
2. Drain
3. Source
4. Drain

2SJ317

Absolute Maximum Ratings (Ta = 25°C)

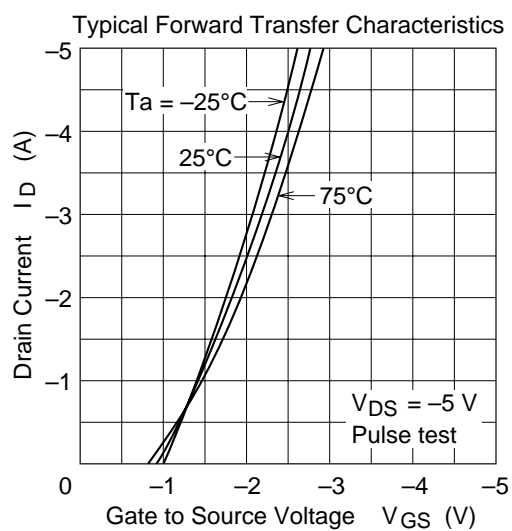
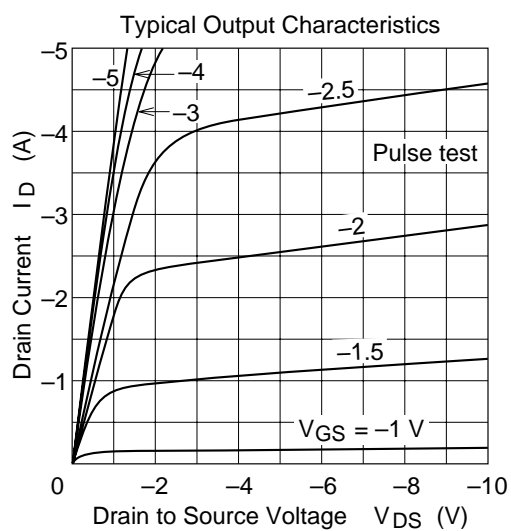
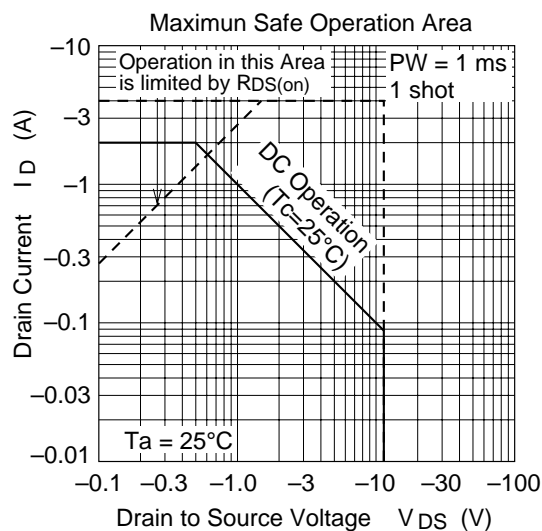
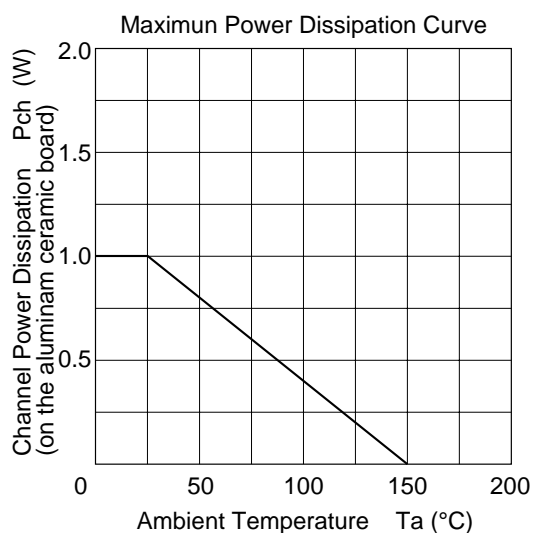
Item	Symbol	Ratings	Unit
Drain to source voltage	V_{DSS}	-12	V
Gate to source voltage	V_{GSS}	-7	V
Drain current	I_D	±2	A
Drain peak current	$I_{D(pulse)}^{*1}$	±4	A
Body to drain diode reverse drain current	I_{DR}	2	A
Channel dissipation	P_{ch}^{*2}	1	W
Channel temperature	T_{ch}	150	°C
Storage temperature	T_{stg}	-55 to +150	°C

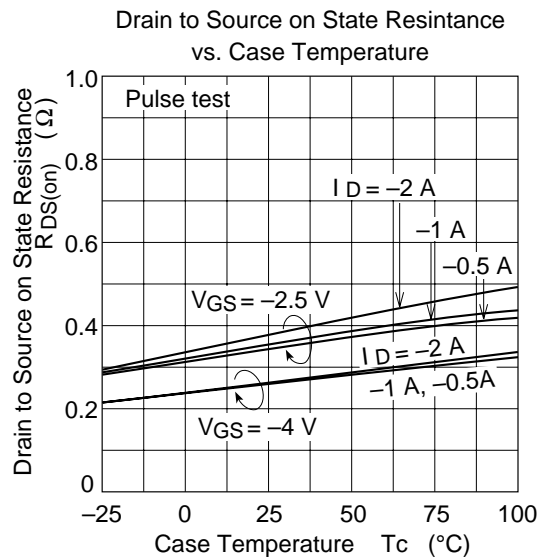
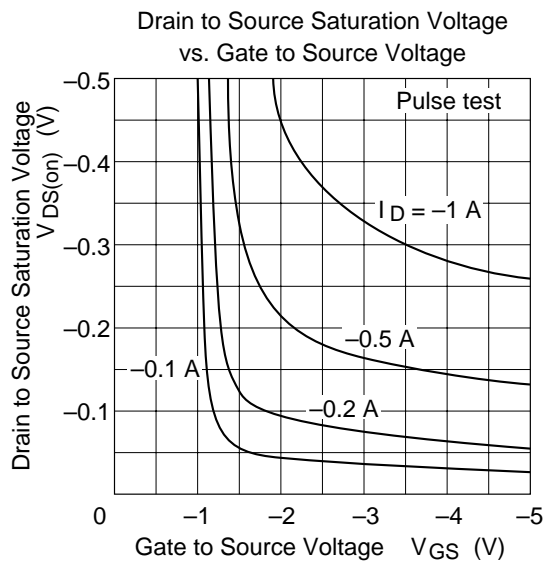
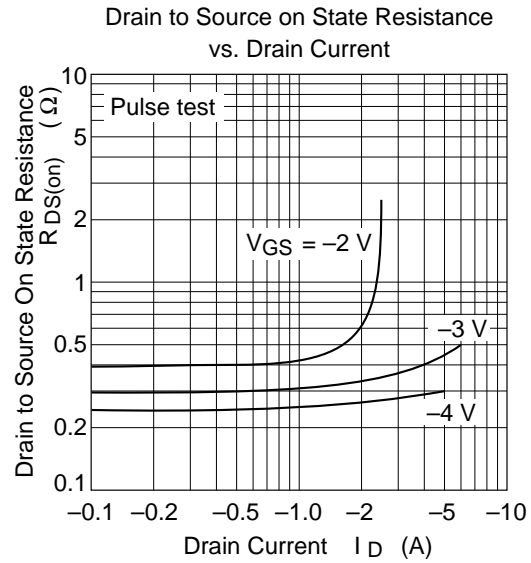
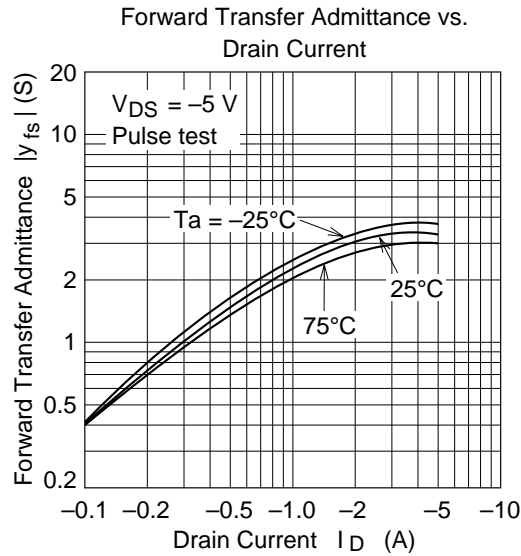
Notes: 1. $PW \leq 100 \mu s$, duty cycle $\leq 10\%$
 2. Value on the alumina ceramic board (12.5×20×0.7 mm).
 3. Marking is "NY".

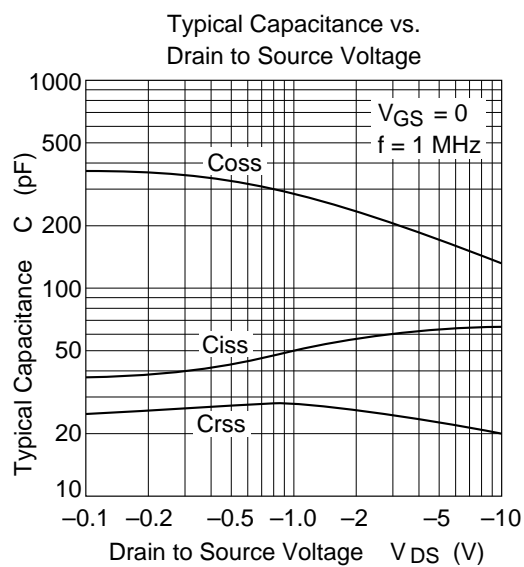
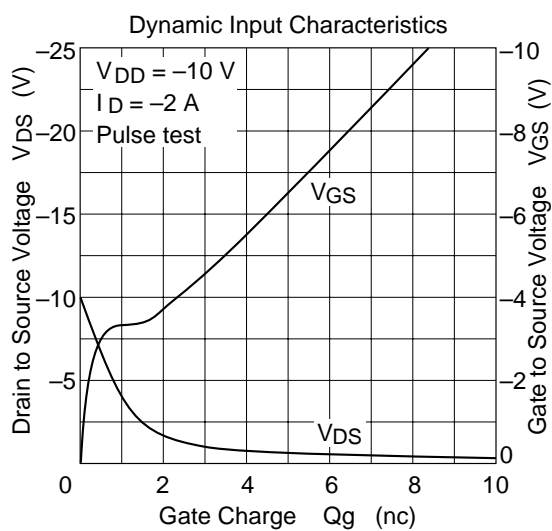
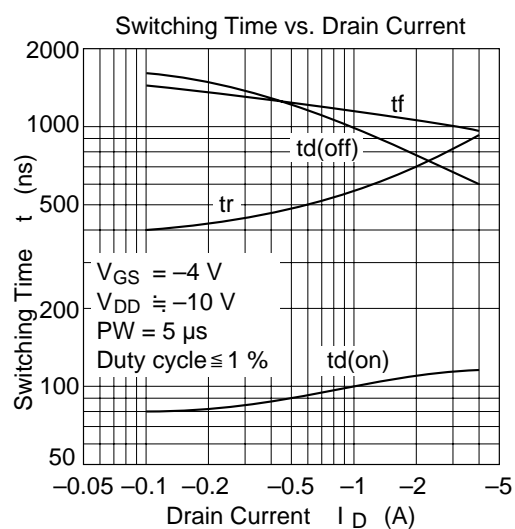
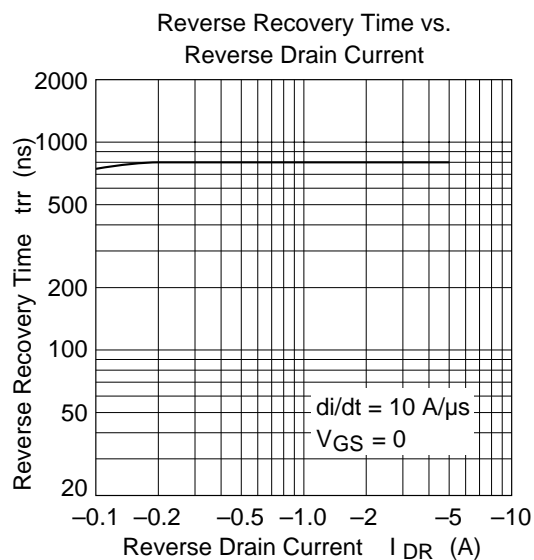
Electrical Characteristics (Ta = 25°C)

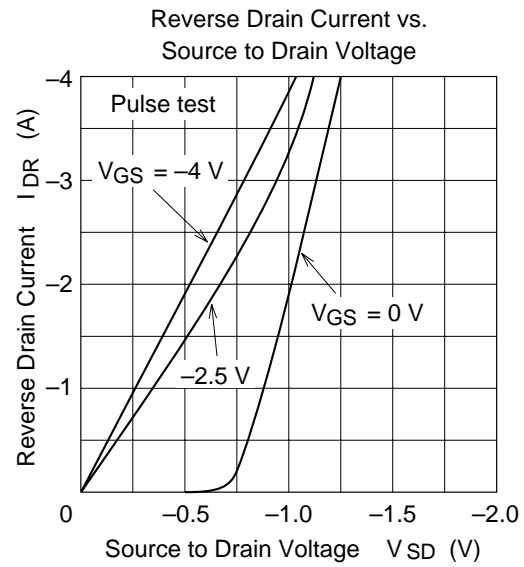
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	-12	—	—	V	$I_D = -1 \text{ mA}$, $V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	±7	—	—	V	$I_G = \pm 10 \mu A$, $V_{DS} = 0$
Gate to source cutoff current	I_{GSS}	—	—	±5	μA	$V_{GS} = \pm 6.5 \text{ V}$, $V_{DS} = 0$
Zero gate voltage drain current	I_{DSS}	—	—	-1	μA	$V_{DS} = -8 \text{ V}$, $V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	-0.4	—	-1.4	V	$I_D = -100 \mu A$, $V_{DS} = -5 \text{ V}$
Static drain to source on state resistance	$R_{DS(on)1}$	—	0.4	0.7	Ω	$I_D = -0.5 \text{ A}^{*1}$, $V_{GS} = -2.2 \text{ V}$
	$R_{DS(on)2}$	—	0.28	0.35	Ω	$I_D = -1 \text{ A}^{*1}$, $V_{GS} = -4 \text{ V}$
Forward transfer admittance	$ y_{fs} $	1.0	2.3	—	S	$I_D = -1 \text{ A}^{*1}$, $V_{DS} = -5 \text{ V}$
Input capacitance	C_{iss}	—	63	—	pF	$V_{DS} = -5 \text{ V}$, $V_{GS} = 0$,
Output capacitance	C_{oss}	—	180	—	pF	$f = 1 \text{ MHz}$
Reverse transfer capacitance	C_{rss}	—	23	—	pF	
Turn-on time	t_{on}	—	500	—	ns	$I_D = -0.2 \text{ A}^{*1}$, $V_{in} = -4 \text{ V}$,
Turn-off time	t_{off}	—	2860	—	ns	$R_L = 51 \Omega$

Note: 1. Pulse test

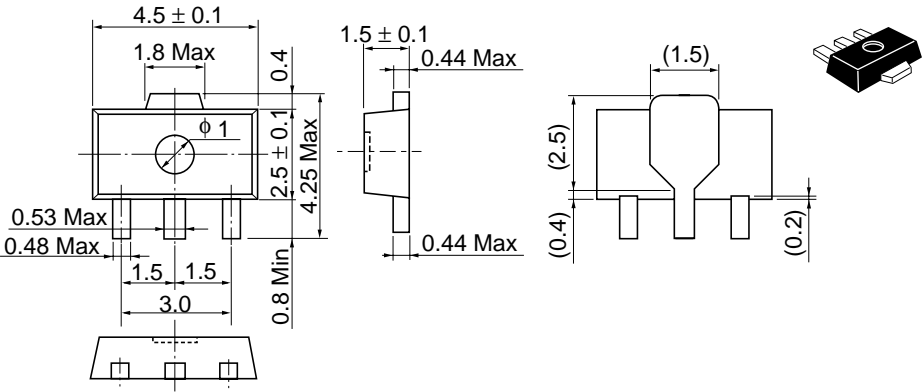








Unit: mm



Hitachi Code	UPAK
JEDEC	—
EIAJ	Conforms
Weight (reference value)	0.050 g

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